NSN 5961-01-463-3070

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View Online at https://aerobasegroup.com/nsn/5961-01-463-3070 **Inclosure Material:** Ceramic **Overall Length:** 0.225 inches **Overall Height:** 0.075 inches **Overall Width:** 0.155 inches **End Application:** 1270-01-142-2855 **Mounting Method:** Press fit **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 75.0 collector to base voltage/static/emitter open and 50.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 800.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 650.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Test Data Document:** 81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 4 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

A110a0
Mil-std (military Standard):

Mil-prf-19500 spec.